SECTION 6 ELECTRICAL CHARACTERISTICS

The AC specifications presented consist of output delays, input setup and hold times, and signal skew times. All signals are specified relative to an appropriate edge of the clock (CL-KO pin) and possibly to one or more other signals.

6.1 MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage	V _{DD}	- 0.3 to + 7.0	V
Input Voltage	V _{in}	- 0.3 to + 7.0	V
Operating Temperature Range MC68302 MC68302C	T _A	0 to 70 - 40 to 85	°C
Storage Temperature Range	T _{stg}	- 55 to + 150	°C

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum-rated voltages to his high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (e.g., either GND or VDD)

6.2 THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance for PGA	Α _L θ	25	°C/W
The interned stance for Y GA	θ _{JC}	2	°C/W
Thermal Resistance for CQFP	θυΑ	40	°C/W
	θ _{JC}	15	°C/W
Thermal Resistance for PQFP	θјΑ	42	°C/W
	θ _{JC}	20	°C/W

$$\begin{split} T_J &= T_A + (P_{D - A}) \\ P_D &= (V_{DD} \cdot I_{DD}) + P_{I/O} \\ \text{where:} \\ P_{I/O} \text{ is the power dissipation on pins.} \\ For T_A &= 70^{\circ}\text{C and } P_{I/O} + 0 \text{ W, } 16.67 \text{ MHz, } 5.5 \text{ V, and CQFP} \\ \text{package, the worst case value of } T_J \text{ is:} \\ T_J &= 70^{\circ}\text{C} + (5.5 \text{ V} \cdot 30 \text{ mA} \cdot 40^{\circ}\text{C/W}) = 98.65\text{C} \end{split}$$

MOTOROLA

MC68302 USER'S MANUAL

6-1

L 6367248 0137462 743 🚥

The average chip-junction temperature, T_J, in °C can be obtained from:

$$T_J = T_A + (P_D \bullet \theta_{JA})(1)$$

where:

T_A = Ambient Temperature, °C

θ, IA = Package Thermal Resistance, Junction to Ambient, °C/W

 $P_D = P_{INT} + P_{I/O}$

P_{INT} = I_{DD} x V_{DD}, Watts—Chip Internal Power

P_{I/O} = Power Dissipation on Input and Output Pins—User Determined

For most applications $P_{I/O} < 0.3 \bullet P_{INT}$ and can be neglected.

If $P_{I/O}$ is neglected, an approximate relationship between P_D and T_J is

$$P_D = K \div (T_J + 273^{\circ}C)(2)$$

Solving equations (1) and (2) for K gives:

$$K = P_D \bullet (T_A + 273^{\circ}C) + \theta_{JA} \bullet P_D^2(3)$$

where K is a constant pertaining to the particular part. K can be determined from equation (3) by measuring P_D (at equilibrium) for a known T_A . Using this value of K, the values of P_D and P_D and P_D are obtained by solving equations (1) and (2) iteratively for any value of P_D .

6.4 POWER DISSIPATION

Characteristic	Symbol	Тур	Max	Unit
Power Dissipation at 25 MHz- Rev C.8μ (see Notes 1 & 2)	PD	85	130	
Power Dissipation at 25 MHz -Rev C.65μ (see Notes 1 & 2)	PD	65		mA
Power Dissipation at 20 MHz-Rev C.8μ (see Notes 1 & 2)	PD	65	90	mA
Power Dissipation at 20 MHz-Rev C.65µ (see Notes 1 & 2)	PD	50	100	mA
Power Dissipation at 16.67 MHz-Rev C.8μ (see Notes 1 & 2)	PD	54	80	mA_
Power Dissipation at 16.67 MHz-Rev C.65µ (see Notes 1 & 2)	PD	44	85	mA
Power Dissipation at 4 MHz-Rev C.8µ (see Notes 1,2 & 3)	PD	40	70	mA
Power Dissipation at 4 MHz-Rev C.65µ (see Notes 1, 2 & 3)	PD	27	-	mA
Power Dissipation at 3.3V 20 MHz-Rev C.65μ (see Note 2)	PD	30	60	mA
Power Dissipation at 3.3V 16.67 MHz-Rev C.65µ (see Note 2)	PD	25	50	mA mA

NOTES:

- 1. Values measured with maximum loading of 130 pF on all output pins. Typical means 5.0 V at 25°C. Maximum means guaranteed maximum over maximum temperature (85°C) and voltage (5.5 V).
- 2. The IMP is tested with the M68000 core executing, all three baud rate generators enabled and clocking at a rate of 64 kHz, and the two general-purpose timers running with a prescaler of 256. Power measurements are not significantly impacted by baud rate generators or timers until their clocking frequency becomes a much more sizable fraction of the system frequency than in these test conditions.
- 3. The M68000 core will not operate at 4 MHz. This is only for low power mode.

MOTOROLA

MC68302 USER'S MANUAL

6367248 0137464 516 🖿

6.5 DC ELECTRICAL CHARACTERISTICS

	Characteristic	Symbol	Min	Max	Unit
Input High Voltage	(Except EXTAL)	V _{IH}	2.0	V _{DD}	V
Input Low Voltage		V _{IL}	V _{SS} - 0.3	0.8	٧
Input High Voltage		V _{CIH}	4.0	VDD	V
Input Low Voltage		V _{CIL}	V _{SS} - 0.3	0.6	V
Input Leakage Cur	·	II _N	_	20	μΑ
Input Capacitance	· · · · · · · · · · · · · · · · · · ·	C _{IN}	_	15	pF
	ge Current (2.4/0.5 V)	I _{TSI}	_	20	μА
Open Drain Leaka		lop	. —	20	μΑ
	ge (I _{OH} = 400 μA) (see Note)	V _{OH}	V _{DD} -1.0		٧
Output Low Voltage (IOL = 3.2 mA)	e A1–A23, PB0–PB11, FC0–FC2, CS0–CS3	V _{OL}		0.5	
(I _{OL.} = 5.3 mA)	IAC, AVEC, BG, RCLK1, RCLK2, RCLK3, TCLK1, TCLK2, TCLK3, RTS1, RTS2, RTS3, SDS2, PA12, RXD2, RXD3, CTS2, CD2, CD3 DREQ, BRG1 AS, UDS, LDS, R/W, BERR BGACK, BCLR, DTACK, DACK, RMC, DO-D15, RESET		_	0.5	V
(I _{OL} = 7.0 mA)	TXD1, TXD2, TXD3			0.5	
$(I_{OL} = 8.9 \text{ mA})$ $(I_{OL} = 3.2 \text{ mA})$	DONE, HALT, BR (as output) CLKO			0.5 0.4	
Output Drive CLK Output Drive ISDN Output Drive All C	N I/F (GCI Mode)	O _{CLK} O _{GC1} O _{ALL}		50 150 130	pF pF pF
Output Drive Dera	ating Factor for CLKO of 0.030 ns/pF ating Factor for CLKO of 0.035 ns/pF ating Factor for All Other Pins 0.035 ns/pF ating Factor for All Other Pins 0.055 ns/pF	O _{KF} O _{KF} O _{KF}	20 50 20 130	50 130 130 220	pF pF pF pF
Power		V _{DD}	4.5	5.5	V
Common		V _{SS}	0	0	V

NOTE: The maximum I_{OH} for a given pin is one-half the I_{OL} rating for that pin. For an I_{OH} between 400 μ A and $I_{OL}/2$ mA, the minimum V_{OH} is calculated as: V_{DD} - (1 + .05 V/mA(I_{OH} -.400 mA)). NOTE: All AC specs are assume an output load of 130pf (except for CLKO).

6.6 DC ELECTRICAL CHARACTERISTICS—NMSI1 IN IDL MODE

Characteristic	Symbol	Min	Max	Unit	Condition
Inj	out Pin Characte	ristics: L1CLK, L	.1SY1, L1RXD, L1	IGR	
Input Low Level Voltage	V _{IL}	-10%	+ 20%		(% of V _{DD})
Input High Level Voltage	V _{IH}	V _{DD} - 20%	V _{DD} + 10%	V	
Input Low Level Current	ΗL	-	± 10	μА	$V_{in} = V_{ss}$
Input High Level Current	II _H	_	± 10	μА	V _{in} = V _{DD}
Ou	tput Pin Charac	teristics: L1TXD,	SDS1- SDS2, L1	RQ	00
Output Low Level Voltage	V _{OL}	0	1.0	V	I _{OL} = 5.0 mA
Output High Level Voltage	V _{OH}	V _{DD} - 1.0	V _{DD}	V	l _{OH} = 400 μA

6.7 AC ELECTRICAL SPECIFICATIONS—CLOCK TIMING

(see Figure 6-1, Figure 6-2, Figure 6-3, and Figure 6-4)

Num.	Characteristic		16.67 MHz		20 MHz		25 MHz			
		Symbol	Min	Max	Min	Max	Min	Max	Unit	
	Frequency of Operation	f	8	16.67	8	20	8	25	MHz	
1	Clock Period (EXTAL) (See note 3)	t _{cyc}	60	125	50	125	40	125	ns	
2, 3	Clock Pulse Width (EXTAL)	t _{CL} , t _{CH}	25	62.5	21	62.5	16	62.5	ns	
4, 5	Clock Rise and Fall Times (EXTAL)	t _{Cr} , t _{Cf}		5		4		4	ns	
5a	EXTAL to CLKO Delay (See Notes 1 and 2)	t _{CD}	2	11	2	9	2	7	ns	

NOTE:

- 1. CLKO loading is 50 pF max.
- 2. CLKO skew from the rising and falling edges of EXTAL will not differ from each other by more than 1 ns, if the EXTAL rise time equals the EXTAL fall time.
- 3. You may not stop the clock input at any time.

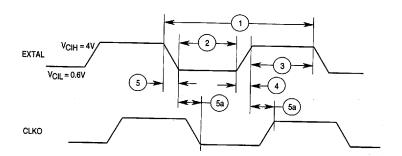


Figure 6-1. Clock Timing Diagram

MOTOROLA

MC68302 USER'S MANUAL

O

6.8 AC ELECTRICAL SPECIFICATIONS—IMP BUS MASTER CYCLES

(see Figure 6-2, Figure 6-3, Figure 6-4, and Figure 6-5))

	e Figure 6-2, Figure 6-3, Figure 6-4, and Figur		16.67	MHz	20 N	ЛНZ	25 N	ЛНZ	
Num.	Characteristic	Symbol	Min	Max	Min	Max	Min	Max	Unit
6	Clock High to FC, Address Valid	†CHFCADV	0	45	0	40	0	30	ns
7	Clock High to Address, Data Bus High Impedance (Maximum)	t _{CHADZ}	_	50	_	42		33	ทธ
8	Clock High to Address, FC Invalid (Minimum)	t _{CHAFI}	0	_	0		0	;	ns
9	Clock High to AS, DS Asserted (see Note 1)	tchsl	3	30	3	25	3	20	ns
11	Address, FC Valid to AS, DS Asserted (Read) AS Asserted Write (see Note 2)	t _{AFCVSL}	15	_	12	_	10	_	ns
12	Clock Low to AS, DS Negated (see Note 1)	t _{CLSH}		30		25		20	ns
13	AS, DS Negated to Address, FC Invalid (see Note 2)	t _{SHAFI}	15		12		10		ns
14	AS (and DS Read) Width Asserted (see Note 2)	t _{SL}	120	_	100	_	80		ns
14A	DS Width Asserted, Write (see Note 2)	tosL	60		50		40	ļ -	ns
15	AS, DS Width Negated (see Note 2)	t _{SH}	60		50		40	ļ —	ns
16	Clock High to Control Bus High Impedance	tcHCZ		50	<u> </u>	42		33	ns
17	AS, DS Negated to R/W Invalid (see Note 2)	t _{SHRH}	15		12		10	<u> </u>	ns
18	Clock High to R/W High (see Note 1)	[‡] CHRH		30		25	_	20	ns
20	Clock High to R/W Low (see Note 1)	t _{CHRL}	<u> </u>	30	<u> </u>	25		20	ns
20A	AS Asserted to R/W Low (Write) (see Notes 2 and 6)	t _{ASRV}		10		10	_	7	ns
21	Address FC Valid to R/W Low (Write) (see Note 2)	t _{AFCVRL}	15		12	_	10	_	ns
22	R/W Low to DS Asserted (Write) (see Note 2)	t _{RLSL}	30		25		20	_	ns
23	Clock Low to Data-Out Valid	t _{CLDO}	_	30		25		20	ns
25	AS, DS, Negated to Data-Out Invalid (Write) (see Note 2)	tshdoi	15	_	12		10	_	ns
26	Data-Out Valid to DS Asserted (Write) (see Note 2)	t _{DOSL}	15	_	12		10		ns
27	Data-In Valid to Clock Low (Setup Time on Read) (see Note 5)	t _{DICL}	7		6		5	_	ns
28	AS, DS Negated to DTACK Negated (Asynchronous Hold) (see Note 2)	tshdah	0	110	0	95	0	75	ns
29	AS, DS Negated to Data-In Invalid (Hold Time on Read)	tshdii	0		0	·	0	_	ns
30	AS, DS Negated to BERR Negated	t _{SHBEH}	0		0		0		ns
31	DTACK Asserted to Data-In Valid (Setup Time) (see Notes 2 and 5)	t _{DALDI}	_	50		42		33	ns
32	HALT and RESET Input Transition Time	t _{RHr} , t _{RH}	4_	150		150	1=	150	ns
33	Clock High to BG Asserted	tcHGL		30		25	<u> </u>	20	ns
34	Clock High to BG Negated	tснан		30		25		20	ns
35	BR Asserted to BG Asserted (see Note 11	t _{BRLGL}	2.5	4.5	2.5	4.5	2.5	4.5	clks
36	BR Negated to BG Negated (see Note 7)	t _{BRHGH}	1.5	2.5	1.5	2.5	1.5	2.5	clks

6-6

MC68302 USER'S MANUAL

MOTOROLA

🗖 6367248 Ol37467 225 🖼

			16.6	7 MHz	20	MHz	25	MHz	
Num.	Characteristic	Symbol	Min	Max	Min	Max	Min	Max	Uni
37	BGACK Asserted to BG Negated	tGALGH	2.5	4.5	2.5	4.5	2.5	4.5	ciks
37A	BGACK Asserted to BR Negated (see Note 8)	†GALBRIH	10	1.5	10	1.5	10	1.5	ns/
38	BG Asserted to Control, Address, Data Bus High Impedance (AS Negated)	t _{GLZ}	_	50	_	42	_	33	ns
39	BG Width Negated	t _{GH}	1.5		1.5		1.5	_	clks
40	BGACK Asserted to Address Valid	tGALAV	15	7 	15		15		ns
41	BGACK Asserted to AS Asserted	t _{GALASA}	30	_	30	_	20	_	ns
44	AS, DS Negated to AVEC Negated	tshvph	0	50	0	42	0	33	ns
46	BGACK Width Low	t _{GAL}	1.5		1.5		1.5		clks
47	Asynchronous Input Setup Time (see Note 5)	t _{ASI}	10	_	10		7	_	ns
48	BERR Asserted to DTACK Asserted (see Notes 2 and 3)	t _{BELDAL}	10		10	_	7	_	ns
53	Data-Out Hold from Clock High	t _{CHDOI}	0		0		0		ns
55	R/W Asserted to Data Bus Impedance Change	t _{RLDBD}	0	_	0	_	0	_	ns
56	HALT/RESET Pulse Width (see Note 4)	t _{HRPW}	10		10	_	10		clks
57	BGACK Negated to AS, DS, R/W Driven	t _{GASD}	1.5		1.5		1.5		ciks
57A	BGACK Negated to FC	t _{GAFD}	1	_	. 1		1	_	clks
58	BR Negated to AS, DS, R/W Driven (see Note 7)	t _{RHSD}	1.5	_	1.5	_	1.5	_	clks
58A	BR Negated to FC (see Note 7)	t _{RHFD}	1	_	1	_	1	_	clks
60	Clock High to BCLR Asserted	t _{CHBCL}	_	30	_	25	_	20	ns
61	Clock High to BCLR High Impedance (See Note 10)	t _{CHBCH}	_	30	-	25	_	20	ns
62	Clock Low (S0 Falling Edge during read) to RMC Asserted	tCLRML	, —	30	_	25	_	20	ns
63	Clock High (during write) to RMC Negated	t _{CHRMH}	_	30		25		20	ns
64 S:	RMC Negated to BG Asserted (see Note 9)	tRMHGL	_	30		25		20	ns

- 1. For loading capacitance of less than or equal to 50 pF, subtract 4 ns from the value given in the maximum columns.
- Actual value depends on clock period since signals are driven/latched on different CLKO edges. To calculate the
 actual spec for other clock frequencies, the user may derive the formula for each specification. First, derive the
 margin factor as:
 M = N(P/2) Sa

where N is the number of one-half CLKO periods between the two events as derived from the timing diagram, P is the rated clock period of the device for which the specs were derived (e.g., 60 ns with a 16.67-MHz device or 50 ns with a 20 MHz device), and Sa is the actual spec in the data sheet. Thus, for spec 14 at 16.67 MHz: M = 5(60 ns/2) - 120 ns = 30 ns.

Once the margin (M) is calculated for a given spec, a new value of that spec (Sn) at another clock frequency with period (Pa) is calculated as:

Sn = N(Pa/2) - M

Thus for spec 14 at 12.5 MHz:

Sn = 5(80 ns/2) - 30 ns = 170 ns.

These two formulas assume a 50% duty cycle. Otherwise, if N is odd, the previous values N(P/2) and N(Pa/2) must be reduced by X, where X is the difference between the nominal pulse width and the minimum pulse width of the EXTAL input clock for that duty cycle.

3. If #47 is satisfied for both DTACK and BERR, #48 may be ignored. In the absence of DTACK, BERR is a

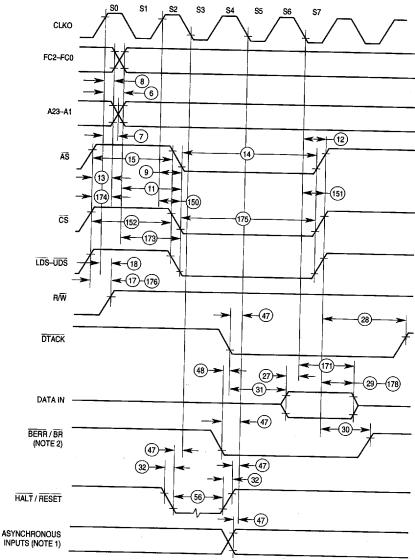
MOTOROLA

MC68302 USER'S MANUAL

6-7

6367248 0137468 161

- synchronous input using the asynchronous input setup time (#47).
- 4. For power-up, the MC68302 must be held in the reset state for 100 ms to allow stabilization of on-chip circuit. After the system is powered up #56 refers to the minimum pulse width required to reset the processor.
- 5. If the asynchronous input setup (#47) requirement is satisfied for DTACK, the DTACK asserted to data setup time (#31) requirement can be ignored. The data must only satisfy the data-in to clock low setup time (#27) for the following clock cycle.
- 6. When AS and R/W are equally loaded (±20%), subtract 5 ns from the values given in these columns.
- 7. The MC68302 will negate BG and begin driving the bus if external arbitration logic negates BR before asserting BGACK.
- 8. The minimum value must be met to guarantee proper operation. If the maximum value is exceeded, BG may be reasserted.
- 9. This specification is valid only when the RMCST bit is set in the SCR register.
- 10.Occurs on S0 of SDMA read/write access when the SDMA becomes bus master.
- 11. Specification may be exceeded during the TAS instruction if the RMCST bit in the SCR is set.



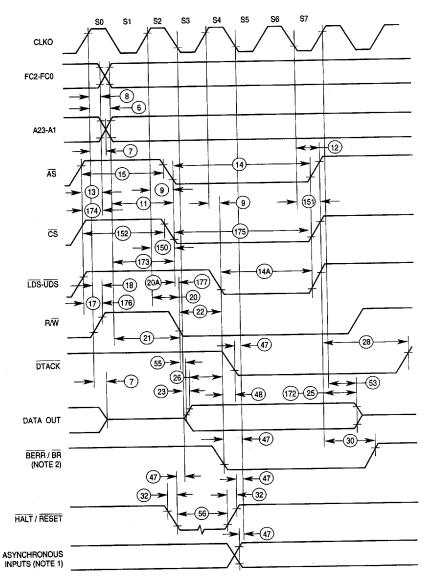
- Setup time for the asynchronous inputs IPL2-IPL0 guarantees their recognition at the next falling edge of the clock.
- 2. BR need fall at this time only to insure being recognized at the end of the bus cycle.
- Timing measurements are referenced to and from a low voltage of 0.8 volt and a high voltage of 2.0 volts, unless otherwise noted. The voltage swing through this range should start outside and pass through the range such that the rise or fall is linear between 0.8 volts and 2.0 volts.

Figure 6-2. Read Cycle Timing Diagram

MOTOROLA

MC68302 USER'S MANUAL

6367248 D137470 81T 🖿



 Timing measurements are referenced to and from a low voltage of 0.8 volt and a high voltage of 2.0 volts, unless otherwise noted. The voltage swing through this range should start outside and pass through the range such that the rise or fall is linear between between 0.8 volt and 2.0 volts.

2. Because of loading variations, RW may be valid after AS even though both are initiated by the rising edge of S2 (specification #20A)

3. Each wait state is a full clock cycle inserted between S4 and S5.

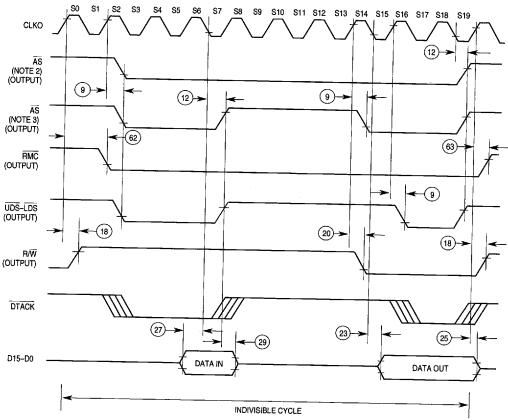
Figure 6-3. Write Cycle Timing Diagram

MC68302 USER'S MANUAL

MOTOROLA

6-10

6367248 0137471 756



- 1. For other timings than RMC, see Figures 6-2 and 6-3.
- 2. RMCST = 0 in the SCR.
- RMCST = 1 in the SCR.
- 4. Wait states may be inserted between S4 and S5 during the write cycle and between S16 and S17 during the read cycle.
- 5. Read-modify-write cycle is generated only by the TAS instruction.

Figure 6-4. Read-Modify-Write Cycle Timing Diagram

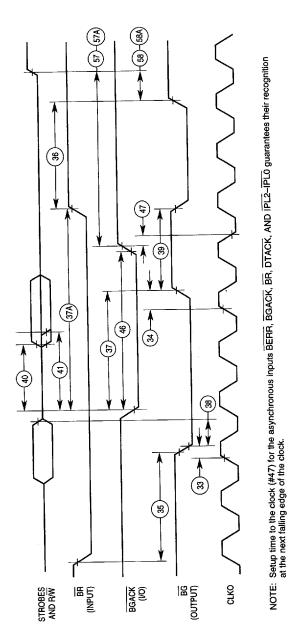


Figure 6-5. Bus Arbitration Timing Diagram

MC68302 USER'S MANUAL

MOTOROLA

6-12

= 6367248 0137473 529 **=**

6.9 AC ELECTRICAL SPECIFICATIONS—DMA (see Figure 6-6 and Figure 6-7)

		·, ·		_ `			94.0	,	
Num.			16.6	7 MHz	20	MHz	25	MHz	
Nuiii.	Characteristic	Symbol	Min	Max	Min	Max	Min	Max	Unit
80	DREQ Asynchronous Setup Time (see Note 1)	t _{REQASI}	15	_	15	-	10		ns
81	DREQ Width Low (see Note 2)	t _{REQL}	2	_	2	_	2		clks
82	DREQ Low to BR Low (see Notes 3 and 4)	tREQLBRL	-	2	_	2	_	2	clks
83	Clock High to BR Low (see Notes 3 and 4)	t _{CHBAL}		30	_	25		20	ns
84	Clock High to BR High Impedance (see Notes 3 and 4)	t _{CHBRZ}	_	30	_	25		20	ns
85	BGACK Low to BR High Impedance (see Notes 3 and 4)	t _{BKLBRZ}	30	_	25	_	20	_	ns
86	Clock High to BGACK Low	t _{CHBKL}	_	30	_	25		20	ns
87	AS and BGACK High (the Latest One) to BGACK Low (when BG is Asserted)	t _{ABHBKL}	1.5	2.5 +30	1.5	2.5 +25	1.5	2.5 +20	clks ns
88	BG Low to BGACK Low (No Other Bus Master) (see Notes 3 and 4)	t _{BGLBKL}	1.5	2.5 +30	1.5	2.5 +25	1.5	2.5	clks
89	BR High Impedance to BG High (see Notes 3 and 4)	t _{BRHBGH}	0	_	0	_	0	_	ns
90	Clock on which BGACK Low to Clock on which AS Low	t _{CLBKLAL}	2	2	2	2	2	2	clks
91	Clock High to BGACK High	tснвкн	_	30		25		20	ns
92	Clock Low to BGACK High Impedance	t _{CLBKZ}		15		15		10	ns
93	Clock High to DACK Low	t _{CHACKL}		30	_	25	_	20	ns
94	Clock Low to DACK High			30	_	25		20	ns
95	Clock High to DONE Low (Output)			30	_	25		20	ns
96	Clock Low to DONE High Impedance			30		25			ns
97	DONE Input Low to Clock Low (Asynchronous Setup)	t _{DNLTCH}	15	_	15	_	10	_	ns
94 95 96	Clock Low to DACK High Clock High to DONE Low (Output) Clock Low to DONE High Impedance DONE Input Low to Clock Low (Asynchro-	tchackl tclackh tchdnl tcldnz toldnz tdnltch	_ _ _	30		25 25			

NOTES:

- 1. DREQ is sampled on the falling edge of CLK in cycle steal and burst modes.
- 2. If #80 is satisfied for DREQ, #81 may be ignored.
- 3. BR will not be asserted while BG, HALT, or BERR is asserted.
- 4. Specifications are for DISABLE CPU mode only.
- 5. DREQ, DACK, and DONE do not apply to the SDMA channels.
- 6. DMA and SDMA read and write cycle timing is the same as that for the M68000 core.

MOTOROLA

MC68302 USER'S MANUAL

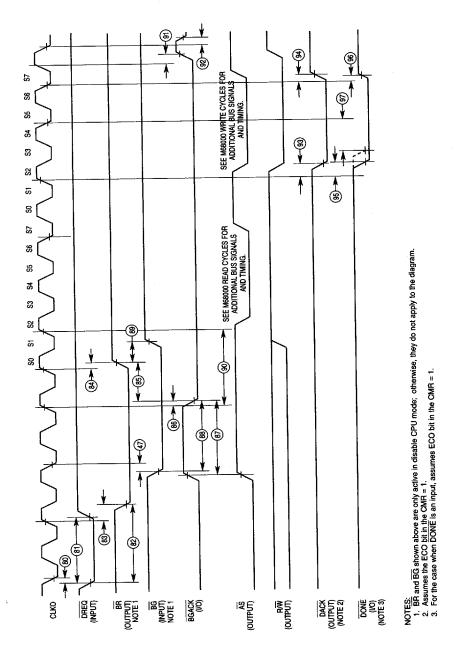


Figure 6-6. DMA Timing Diagram (IDMA)

6-14 MC68302 USER'S MANUAL 6367248 0137475 3T1 ■

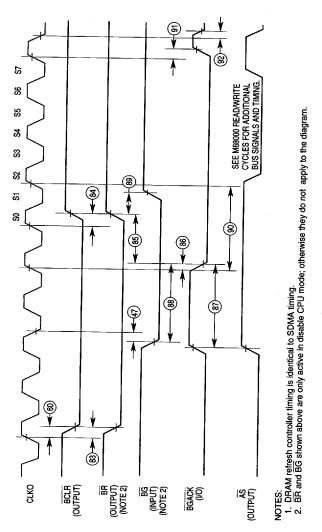


Figure 6-7. DMA Timing Diagram (SDMA)

MOTOROLA

MC68302 USER'S MANUAL

6.10 AC ELECTRICAL SPECIFICATIONS—EXTERNAL MASTER INTERNAL ASYNCHRONOUS READ/WRITE CYCLES

(see Figure 6-8 and Figure 6-9)

			16.67	MHz	20 I	VIHz	25	ИHz	
Num.	Characteristic	Symbol	Min	Max	Min	Max	Min	Max	Unit
100	R/W Valid to DS Low	t _{RWVDSL}	0		0	_	0		ns
101	DS Low to Data-In Valid	t _{DSLDIV}		30	_	25		20	ns
102	DTACK Low to Data-In Hold Time	t _{DKLDH}	0		0	_	0		ns
103	AS Valid to DS Low	tasydsl	0	_	0		0		ns
104	DTACK Low to AS, DS High	t _{DKLDSH}	0		0		0		ns
105	DS High to DTACK High	† _{DSHDKH}	_	45	_	40		30	ns
106	DS Inactive to AS Inactive	t _{DSIASI}	0	<u>-</u>	0		0		ns
107	DS High to R/W High	t _{DSHRWH}	0		0	_	0		ns
108	DS High to Data High Impedance	[‡] DSHDZ	_	45	_	40	_	30	ns
108A	DS High to Data-Out Hold Time (see Note)	t _{DSHDH}	0	_	0		0	_	ns
109A	Data Out Valid to DTACK Low	t _{DOVDKL}	15	_	15	_	10	_	ns

NOTE: If \overline{AS} is negated before \overline{DS} , the data bus could be three-stated (spec 126) before \overline{DS} is negated.

■ 6367248 0137477 174 **■**

MC68302 USER'S MANUAL

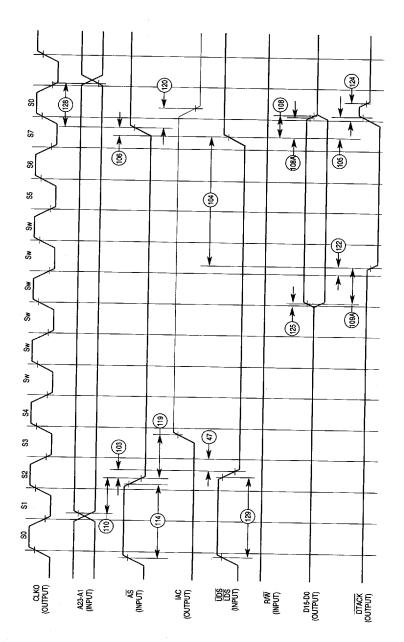


Figure 6-8. External Master Internal Asynchronous Read Cycle Timing Diagram

MOTOROLA MC68302 USER'S MANUAL 6-17

| 6367248 Ol37478 OOO 🖿

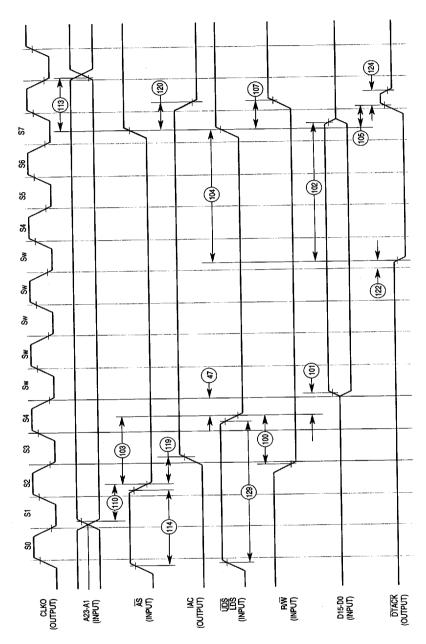


Figure 6-9. External Master Internal Asynchronous Write Cycle Timing Diagram

■ 6367248 D137479 T47 ■

6-18 MC68302 USER'S MANUAL

6.11 AC ELECTRICAL SPECIFICATIONS—EXTERNAL MASTER INTERNAL SYNCHRONOUS READ/WRITE CYCLES

(see Figure 6-10, Figure 6-11, and Figure 6-12)

			16.6	7 MHz	20	MHz	25	MHz	
Num.	Characteristic	Symbol	Min	Max	Min	Max	Min	Max	Unit
110	Address Valid to AS Low	tavasl	15	_	12		10	 	ns
111	AS Low to Clock High	taslch	30	_	25	-	20		ns
112	Clock Low to AS High	t _{CLASH}	_	45		40	_	30	ns
113	AS High to Address Hold Time on Write	tashah	0		0	_	0	-	ns
114	AS Inactive Time	t _{ASH}	1	-	1		1		cik
115	UDS/LDS Low to Clock High (see Note 2)	t _{SLCH}	40		33		27	<u> </u>	ПS
116	Clock Low to UDS/LDS High	t _{CLSH}		45		40		30	ns
117	R/W Valid to Clock High (see Note 2)	t _{RWVCH}	30		25		20	_	ns
118	Clock High to R/W High	tchrwh		45		40		30	ns
119	AS Low to IAC High	†ASLIAH		40		35		27	ns
120	AS High to IAC Low	tashial		40	_	35		27	ns
121	AS Low to DTACK Low (0 Wait State)	t _{ASLDTL}		45		40		30	пs
122	Clock Low to DTACK Low (1 Wait State)	[‡] CLDTL		30		25		20	ns
123	AS High to DTACK High	t _{ASHDTH}		45	_	40		30	ns
124	DTACK High to DTACK High Impedance	t _{DTHDTZ}	_	15		15		10	ns
125	Clock High to Data-Out Valid	tCHDOV		30		25		20	ns
126	AS High to Data High Impedance	t _{ASHDZ}	_	45		40		30	ns
127	AS High to Data-Out Hold Time	†ASHDOI	0		0		0	=	ns
128	AS High to Address Hold Time on Read	t _{ASHAI}	0	_	0		0	\rightarrow	ns
129	UDS/LDS Inactive Time	t _{SH}	1		1	_	1	_	cik
130	Data-In Valid to Clock Low	tCLDIV	30		25	_	20	+	ns
131	Clock Low to Data-In Hold Time	tCLDIH	15		12		10		ns

Synchronous specifications above are valid only when SAM = 1 in the SCR.

= 6367248 0137480 769 **==**

MOTOROLA

MC68302 USER'S MANUAL

^{2.} It is required that this signal not be asserted prior to the previous rising CLKO edge (i.e., in the previous clock cycle). It must be recognized by the IMP no sooner than the rising CLKO edge shown in the diagram.

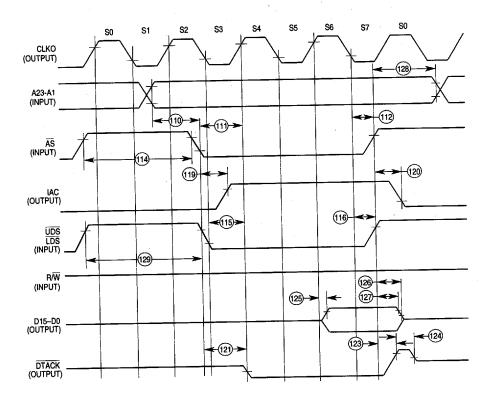


Figure 6-10. External Master Internal Synchronous Read Cycle Timing Diagram

6367248 Ol374816T5 📰

MC68302 USER'S MANUAL

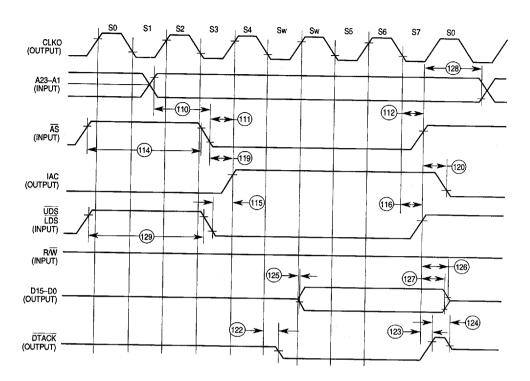


Figure 6-11. External Master Internal Synchronous Read Cycle Timing Diagram (One Wait State)

6367248 0137482 531 🖿

MOTOROLA

MC68302 USER'S MANUAL

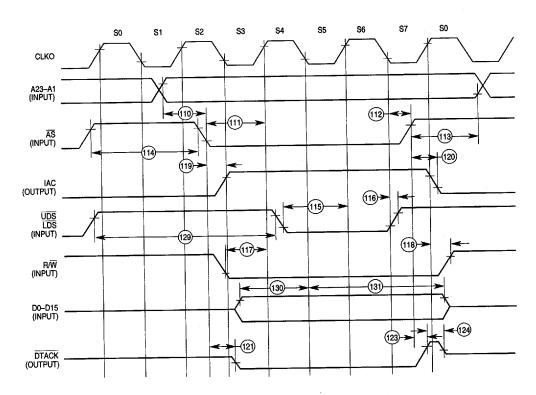


Figure 6-12. External Master Internal Synchronous Write Cycle Timing Diagram

6367248 0137483 478 📟

6-22 MC68302 USER'S MANUAL

6.12 AC ELECTRICAL SPECIFICATIONS—INTERNAL MASTER INTERNAL READ/WRITE CYCLES (see Figure 6-13)

	Characteristic		16.67 MHz		20 MHz		25 MHz		
Num.		Symbol	Min	Max	Min	Max	Min	Max	Unit
140	Clock High to IAC High	tchiah	_	40	_	35		27	ns
141	Clock Low to IAC Low	tCLIAL		40		35		27	ns
142	Clock High to DTACK Low	tCHDTL	_	45		40		30	ns
143	Clock Low to DTACK High	[‡] CLDTH		40		35		27	ns
144	Clock High to Data-Out Valid	tchdov		30		25		20	ns
145	AS High to Data-Out Hold Time	t _{ASHDOH}	0	_	0		0		ns

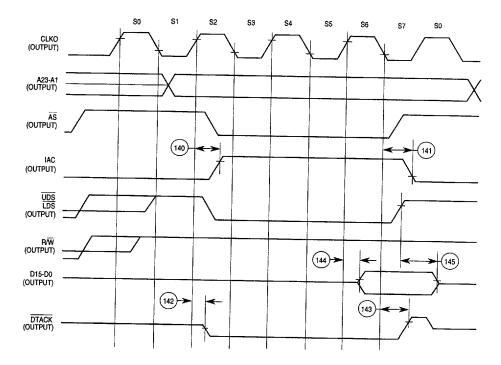


Figure 6-13. Internal Master Internal Read/Write Cycle Timing Diagram

MOTOROLA

MC68302 USER'S MANUAL

6-23

6367248 0137484 304 🚥

6.13 AC ELECTRICAL SPECIFICATIONS—CHIP-SELECT TIMING INTERNAL MASTER (see Figure 6-14)

			16.67	MHz	20 MHz		25 MHz		
Num.	Characteristic	Symbol	Min	Мах	Min	Max	Min	Max	Unit
150	Clock High to CS, IACK Low (see Note 2)	[†] CHCSIAKL	0	40	0	35	0	27	ns
151	Clock Low to CS, IACK High (see Note 2)	[†] CLCSIAKH	0	40	0	35	0	27	ns
152	CS Width Negated	t _{CSH}	60		50		40		ns
153	Clock High to DTACK Low (0 Wait State)	t _{CHDTKL}	_	45	_	40	_	30	ns
154	Clock Low to DTACK Low (1–6 Wait States)	† _{CLDTKL}	_	30	_	25	_	20	ns
155	Clock Low to DTACK High	t _{CLDTKH}		40		35		27	ns
156	Clock High to BERR Low (see Note 1)	tCHBERL		40		35		27	ns
157	Clock Low to BERR High Impedance (see Note 1)	t _{CLBERH}	_	40	_	35	_	27	ns
158	DTACK High to DTACK High Impedance	t _{DTKHDTKZ}		15		15		10	ns
171	Input Data Hold Time from S6 Low	tIDHCL	5	_	5	_	5	_	ns
172	CS Negated to Data-Out Invalid (Write)	t _{CSNDOI}	10	_	10		7		ns
173	Address, FC Valid to CS Asserted	tarvcsa	15		15	<u> </u>	15	<u> </u>	ns
174	CS Negated to Address, FC Invalid	tcsnafi	15	_	15	_	12	_	ns
175	CS Low Time (0 Wait States)	t _{CSLT}	120	_	100		80		ns
176	CS Negated to R/W Invalid	tcsnawi	10		10		7	-	ns
177	CS Asserted to R/W Low (Write)	tcsanwl	_	10	_	10	-	8	ns
178	CS Negated to Data-In Invalid (Hold Time on Read)	t _{CSNDII}	0	_	0		0		ns

NOTE:

- 1. This specification is valid only when the ADCE or WPVE bits in the SCR are set.
- 2. For loading capacitance less than or equal to 50 pF, subtract 4 ns from the maximum value given.
- 3. Since AS and CS are asserted/negated on the same CLKO edges, no AS to CS relative timings can be specified. However, CS timings are given relative to a number of other signals, in the same manner as AS. See Figure 6-2 and Figure 6-3 for diagrams.

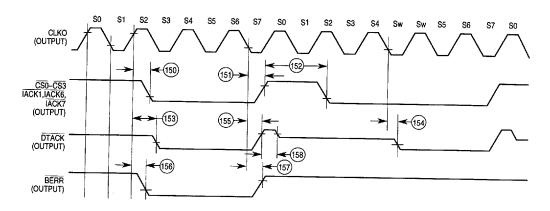


Figure 6-14. Internal Master Chip-Select Timing Diagram

6.14 AC ELECTRICAL SPECIFICATIONS—CHIP-SELECT TIMING EXTERNAL MASTER (see Figure 6-15)

			16.67	7 MHz	20	MHz	25	MHz		
Num.	Characteristic	Symbol	Min	Max	Min	Max	Min	Max	Unit	
154	Clock Low to DTACK Low (1-6 Wait States)	tCLDTKL		30	_	25		20	ns	
160	AS Low to CS Low	tASLCSL	_	30	_	25	_	20	ns	
161	AS High to CS High	t _{ASHCSH}		30		25		20	ns	
162	Address Valid to AS Low	tavasl	15		12		10		ns	
163	R/W Valid to AS Low (see Note 1)	t _{RWVASL}	15	_	12		10		ns	
164	AS Negated to Address Hold Time	t _{ASHAI}	0	_	0		0	_	ns	
165	AS Low to DTACK Low (0 Wait State)	t _{ASLDTKL}	_	45	_	40		30	ns	
167	AS High to DTACK High	t _{ASHDTKH}		30		25		20	ns	
168	AS Low to BERR Low (see Note 2)	t _{ASLBERL}	_	30		25	_	20	ns	
169	AS High to BERR High Impedance (see Notes 2 and 3)	t _{ASHBERH}	-	30		25		20	ns	

NOTES:

- 1. The minimum value must be met to guarantee write protection operation.
- 2. This specification is valid when the ADCE or WPVE bits in the SCR are set.
- 3. Also applies after a timeout of the hardware watchdog.

MOTOROLA

MC68302 USER'S MANUAL

6-25

| 6367248 0137486187 📟

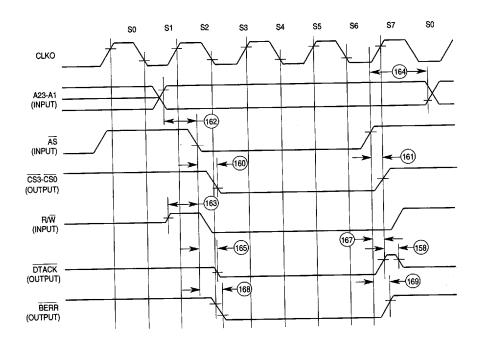


Figure 6-15. External Master Chip-Select Timing Diagram

6.15 AC ELECTRICAL SPECIFICATIONS—PARALLEL I/O

(see Figure 6-16)

			16.67 MHz		20 MHz		25 MHz			
Num.	Characteristic	Symbol	Min	Max	Min	Max	Min	Max	Unit	
180	Input Data Setup Time (to Clock Low)	t _{DSU}	20	_	20	_	14	_	ns	
181	Input Data Hold Time (from Clock Low)	t _{DH}	10		10		19	_	ns	
182	Clock High to Data-out Valid (CPU Writes Data, Control, or Direction)	t _{CHDOV}	_	35		30	_	24	ns	

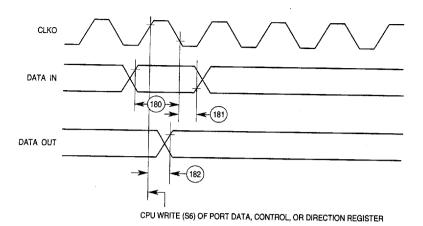


Figure 6-16. Parallel I/O Data-In/Data-Out Timing Diagram

6.16 AC ELECTRICAL SPECIFICATIONS—INTERRUPTS

(see Figure 6-17)

			16.67 MHz		20 MHz		25 MHz		
Num.	Characteristic	Symbol	Min	Max	Min	Max	Min	Max	Unit
190	Interrupt Pulse Width Low IRQ (Edge Triggered Mode) or PB8-11	t pw	50	_	42		34	_	ns
191	Minimum Time Between Active Edges	t _{AEMT}	3	_	3		3		clk

NOTE: Setup time for the asynchronous inputs IPL2-IPL0 and AVEC guarantees their recognition at the next falling edge of the clock.

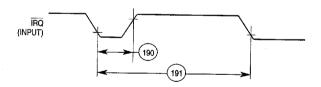


Figure 6-17. Interrupts Timing Diagram

MOTOROLA

MC68302 USER'S MANUAL

6.17 AC ELECTRICAL SPECIFICATIONS—TIMERS

(see Figure 6-18)

Num. 200 201 202 203			16.67	MHz	20	MHz	25 1	MHz	<u> </u>	
Num.	Characteristic	Symbol	Min	Max	Min	Max	Min	Max	Unit	
200	Timer Input Capture Pulse Width	t _{TPW}	50	_	42	_	34	_	ns	
201	TIN Clock Low Pulse Width	t _{TICLT}	50		42		34	_	ns	
202	TIN Clock High Pulse Width and Input Capture High Pulse Width	t _{TICHT}	2	_	2	_	2		clk	
203	TIN Clock Cycle Time	t _{cyc}	3		3		3		clk	
204	Clock High to TOUT Valid	tснтоv	-	35		30		24	ns	
205	FRZ Input Setup Time (to Clock High) (see Note 1)	t _{FRZSU}	20	_	20		14	_	ns	
206	FRZ Input Hold Time (from Clock High)	t _{FRZHT}	10		10	_	7	<u> </u>	ns	

NOTES:

1. FRZ should be negated during total system reset.

2. The TIN specs above do not apply to the use of TIN1 as a baud rate generator input clock. In such a case, specifications 1-3 may be used.

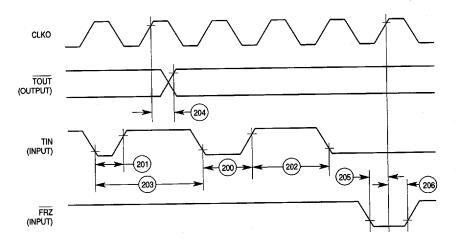


Figure 6-18. Timers Timing Diagram

6.18 AC ELECTRICAL SPECIFICATIONS—SERIAL COMMUNICATIONS PORT (see Figure 6-19).

		16.67	7 MHz	20	MHz	25		
Num.	Characteristic	Min	Max	Min	Max	Min	Max	Unit
250	SPCLK Clock Output Period	4	64	4	64	4	64	clks
251	SPCLK Clock Output Rise/Fall Time	0	15	0	10	0	8	ns
252	Delay from SPCLK to Transmit (see Note 1)	0	40	0	30	0	24	ns
253	SCP Receive Setup Time (see Note 1)	40		30		24		ns
254	SCP Receive Hold Time (see Note 1)	10		8		7	<u> </u>	ns

NOTES:

- 1. This also applies when SPCLK is inverted by CI in the SPMODE register.
- 2. The enable signals for the slaves may be implemented by the parallel I/O pins.

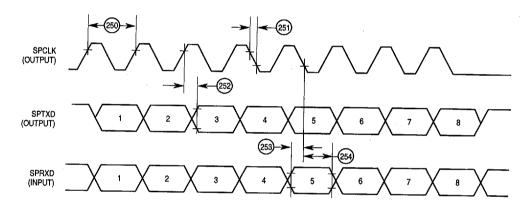


Figure 6-19. Serial Communication Port Timing Diagram

MOTOROLA

MC68302 USER'S MANUAL

6.19 AC ELECTRICAL SPECIFICATIONS—IDL TIMING (All timing measurements,

unless otherwise specified, are referenced to the L1CLK at 50% point of VDD) (see Figure 6-20).

		16.67	MHz	20 N	ЛНZ	25 N	/Hz	
Num.	Characteristic	Min	Max	Min	Max	Min	Max	Unit
260	L1CLK (IDL Clock) Frequency (see Note 1)	_	6.66	_	8		10	MHz
261	L1CLK Width Low	55	1	45		37		ns
262	L1CLK Width High (see Note 3)	P+10		P+10		P+10	_	ns
263	L1TXD, L1RQ, SDS1-SDS2 Rising/Falling Time	_	20		17	_	14	ns
264	L1SY1 (sync) Setup Time (to L1CLK Falling Edge)	30		25		20	_	ns
265	L1SY1 (sync) Hold Time (from L1CLK Falling Edge)	50	_	40		34		ns
266	L1SY1 (sync) Inactive Before 4th L1CLK	0	_	0	_	0		ns
267	L1TxD Active Delay (from L1CLK Rising Edge)	0	75	0	65	0	50	ns
268	L1TxD to High Impedance (from L1CLK Rising Edge) (see Note 2)	0	50	0	42	0	34	ns
269	L1RxD Setup Time (to L1CLK Falling Edge)	50	_	42	<u> </u>	34		ns
270	L1RxD Hold Time (from L1CLK Falling Edge)	50		42		34		ns
271	Time Between Successive IDL syncs	20		20		20		L1CLK
272	L1RQ Valid before Falling Edge of L1SY1	1	 	1	_	1_	_	L1CLK
273	L1GR Setup Time (to L1SY1 Falling Edge)	50	-	42		34		ns
274	L1GR Hold Time (from L1SY1 Falling Edge)	50		42	<u> </u>	34	<u> </u>	ns
275	SDS1-SDS2 Active Delay from L1CLK Rising Edge	10	75	10	65	7	50	ns
276	SDS1-SDS2 Inactive Delay from L1CLK Falling Edge	10	75	10	65	7	50	ns

NOTES:

1. The ratio CLKO/L1CLK must be greater than 2.5/1.

MOTOROLA

^{2.} High impedance is measured at the 30% and 70% of V_{DD} points, with the line at $V_{DD}/2$ through 10K in parallel with 130 pF.

^{3.} Where P = 1/CLKO. Thus, for a 16.67-MHz CLKO rate, P = 60 ns.

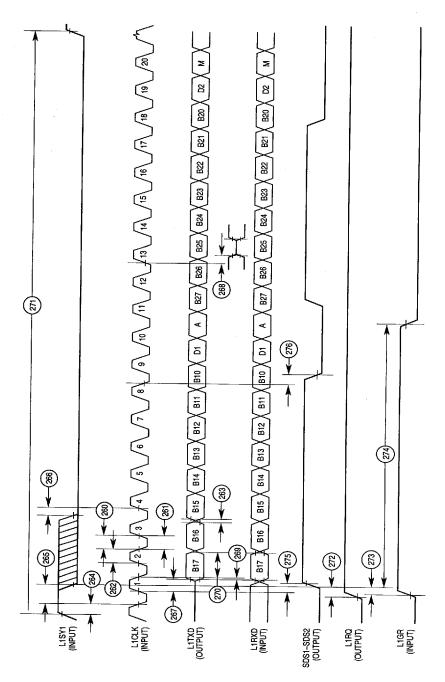


Figure 6-20. IDL Timing Diagram

MOTOROLA MC68302 USER'S MANUAL

6-31

■ 6367248 0137492 480 **■**

6.20 AC ELECTRICAL SPECIFICATIONS—GCI TIMING

GCI supports the NORMAL mode and the GCI channel 0 (GCN0) in MUX mode. Normal mode uses 512 kHz clock rate (256K bit rate). MUX mode uses 256 x n - 3088 kbs (clock rate is data rate x 2). The ratio CLKO/L1CLK must be greater than 2.5/1 (see Figure 6-21).

		16.67	MHz	20 N	ЛHz	25 N	ЛHz	
Num.	Characteristic	Min	Max	Min	Max	Min	Max	Unit
	L1CLK GCI Clock Frequency (Normal Mode) (see Note 1)		512	_	512		512	kHz
280	L1CLK Clock Period Normal Mode (see Note 1)	1800	2100	1800	2100	1800	2100	ns
281	£1CLK Width Low/High Normal Mode	840	1450	840	1450	840	1450	ns
282	L1CLK Rise/Fall Time Normal Mode (see Note 4)		_					ns
	L1CLK (GCI Clock) Frequency (MUX Mode) (see Note 1)	_	6.668	_	6.668	_	6.668	MHz
280	L1CLK Clock Period MUX Mode (see Note 1)	150		150		150		ns
281	L1CLK Width Low MUX Mode	55	<u> </u>	55		55		ns
281A	L1CLK Width High MUX Mode (see Note 5)	P+10		P+10		P+10		ns
282	L1CLK Rise/Fall Time MUX Mode (see Note 4)	_			<u> </u>			ns
283	L1SY1 Sync Setup Time to L1CLK Falling Edge	30		25		20		ns
284	L1SY1 Sync Hold Time from L1CLK Falling Edge	50	—	42		34		ns
285	L1TxD Active Delay (from L1CLK Rising Edge) (see Note 2)	0	100	0	85	0	70	ns
286	L1TxD Active Delay (from L1SY1 Rising Edge) (see Note 2)	0	100	0	85	0	70	ns
287	L1RxD Setup Time to L1CLK Rising Edge	20	_	17		14		ns
288	L1RxD Hold Time from L1CLK Rising Edge	50	_	42		34	<u> </u>	ns
289	Time Between Successive L1SY1in Normal SCIT Mode		=	64 192	_	64 192		L1CLK L1CLK
290	SDS1-SDS2 Active Delay from L1CLK Rising Edge (see Note 3)	10	90	10	75	7	60	ns
291	SDS1-SDS2 Active Delay from L1SY1 Rising Edge (see Note 3)	10	90	10	75	7	60	ns
292	SDS1–SDS2 Inactive Delay from L1CLK Falling Edge	10	90	10	75	7	60	ns
293	GCIDCL (GCI Data Clock) Active Delay	0	50	0	42	0	34	ns

NOTES

- 1. The ratio CLKO/L1CLK must be greater than 2.5/1.
- 2. Condition $C_L = 150$ pF. L1TD becomes valid after the L1CLK rising edge or L1SY1, whichever is later.
- 3.SDS1-SDS2 become valid after the L1CLK rising edge or L1SY1, whichever is later.
- 4.Schmitt trigger used on input buffer.
- 5. Where P = 1/CLKO. Thus, for a 16.67-MHz CLKO rate, P = 60 ns.

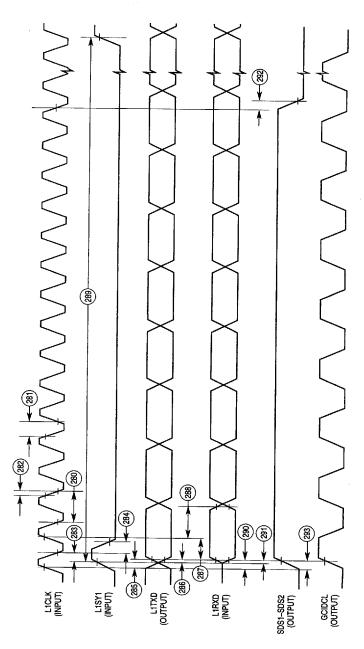


Figure 6-21. GCI Timing Diagram

MOTOROLA

MC68302 USER'S MANUAL

6-33

■ 6367248 0337494 253 **■**

6.21 AC ELECTRICAL SPECIFICATIONS—PCM TIMING

There are two sync types:

Short Frame—Sync signals are one clock cycle prior to the data Long Frame—Sync signals are N-bits that envelope the data, N > 0; see Figure 6-22 and Figure 6-23).

		16.67	MHz	20 N	ЛНZ	25 N	MHz	
Num.	Characteristic	Min	Max	Min	Max	Min	Max	Unit
300	L1CLK (PCM Clock) Frequency (see Note 1)	_	6.66	-	8.0	_	10.0	MHz
301	L1CLK Width Low	55	_	45	_	37		ns
301A	L1CLK Width High (see Note 4)	P+10	<u> </u>	P+10	_	P+10		ns
302	L1SY0-L1SY1 Setup Time to L1CLK Rising Edge	0	_	0	_	0		ns
303	L1SY0-L1SY1 Hold Time from L1CLK Falling Edge	40	_	33	_	27		ns
304	L1SY0-L1SY1 Width Low	1	_	1_	-	1		L1CLK
305	Time Between Successive Sync Signals (Short Frame)	8	_	8	_	8		L1CLK
306	L1TxD Data Valid after L1CLK Rising Edge (see Note 2)	0	70	0	60	0	47	ns
307	L1TxD to High Impedance (from L1CLK Rising Edge)	0 .	50	0	42	0	34	ns
308	L1RxD Setup Time (to L1CLK Falling Edge) (see Note 3)	20	_	17	_	14		ns
309	L1RxD Hold Time (from L1CLK Falling Edge) (see Note 3)	50	_	42	_	34		ns

NOTES:

- 1. The ratio CLK/L1CLK must be greater than 2.5/1.
- 2. L1TxD becomes valid after the L1CLK rising edge or the sync enable, whichever is later, if long frames are used. This note should only be used if the user can guarantee that only one sync pin (L1SY0 and L1SY1) is changed simultaneously in the selection and de-selection of the desired PCM channel time slot. A safe example of this is using only PCM CH-1. Another example is using CH-1 and CH-2 only, where CH-1 and CH-2 are not contiguous on the PCM highway.
- 3. Specification valid for both sync methods.
- 4. Where P = 1/CLKO. Thus, for a 16.67-MHz CLKO rate, P = 60 ns.

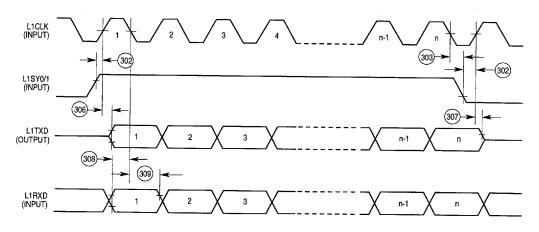
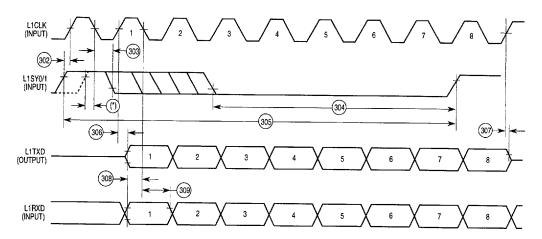


Figure 6-22. PCM Timing Diagram (SYNC Envelopes Data)



NOTE: (*) If L1SYn is guaranteed to make a smooth low to high transition (no spikes) while the clock is high, setup time can be defined as shown (min 20 ns):

Figure 6-23. PCM Timing Diagram (SYNC Prior to 8-Bit Data)

MOTOROLA

MC68302 USER'S MANUAL

6-35

■ 6367248 0137496 026 ■

6.22 AC ELECTRICAL SPECIFICATIONS—NMSI TIMING

The NMSI mode uses two clocks, one for receive and one for transmit. Both clocks can be internal or external. When t he clock is internal, it is generated by the internal baud rate generator and it is output on TCLK or RCLK. All the timing is related to the external clock pin. The timing is specified for NMSI1. It is also valid for NMSI2 and NMSI3 (see Figure 6-24).

		16.67	MHz	16.67	MHz	20	ИHz	20 N	ИНz	25 l	ИНZ	25 N	ИHz			
Num.	Characteristic		rnal ock		External Clock		rnal ock	External Internal Clock Clock				***********		External Clock		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max			
315	RCLK1 and TCLK1 Fre- quency (see Note 1)		5.55	_	6.668		6.66	_	8		8.33	_	10	MHz		
316	RCLK1 and TCLK1 Low (see Note 4)	65		P+10	-	5 5		P+10	_	45		P+10	_	ns		
316a	RCLK1 and TCLK1 High	65	_	55		55	_	45	<u> </u>	45		35		ns		
317	RCLK1 and TCLK1 Rise/Fall Time (see Note 3)	_	20	_			17	_			14	_	_	ns		
318	TXD1 Active Delay from TCLK1 Falling Edge	0	40	0	70	0	30	0	50	0	25	0	40	ns		
319	RTS1 Active/Inactive Delay from TCLK1 Falling Edge	0	40	0	100	0	30	0	80	0	25	0	65	ns		
320	CTS1 Setup Time to TCLK1 Rising Edge	50	_	10		40	_	7		35	_	7	_	ns		
321	RXD1 Setup Time to RCLK1 Rising Edge	50	-	10	-	40		7	_	35		7	_	ns		
322	RXD1 Hold Time from RCLK1 Rising Edge (see Note 2)	10	_	50		7	_	40	_	7	_	35	_	ns		
323	CD1 Setup Time to RCLK1 Rising Edge	50	_	10	_	40		7		35		7	_	ns		

NOTES:

- 1. The ratio CLKO/TCLK1 and CLKO/RCLK1 must be greater than or equal to 2.5/1 for external clock. The input clock to the baud rate generator may be either an internal clock or TIN1, and may be as fast as EXTAL. However, the output of the baud rate generator must provide a CLKO/TCLK1 and CLKO/RCLK1 ratio greater than or equal to 3/1. In asynchronous mode (UART), the bit rate is 1/16 of the TCLK1/RCLK1 clock rate.
- 2. Also applies to \overline{CD} hold time when \overline{CD} is used as an external sync in BISYNC or totally transparent mode.
- 3. Schmitt triggers used on input buffers.
- 4. Where P = 1/CLKO. Thus, for a 16.67-MHz CLKO rate, P = 60 ns.

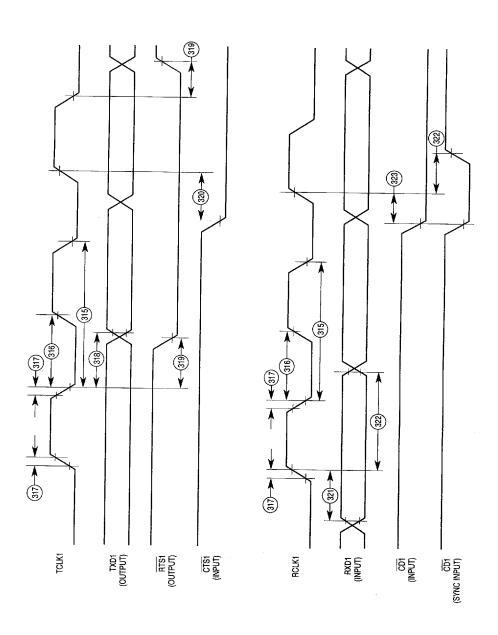


Figure 6-24. NMSI Timing Diagram

MOTOROLA

MC68302 USER'S MANUAL

6-37

■ 6367248 0137498 9T9 **■**